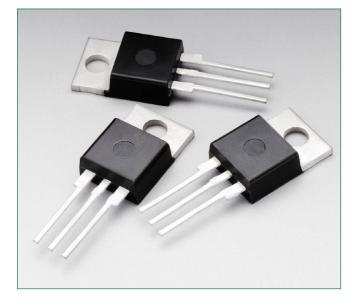


# BTA08-600BW3G, BTA08-800BW3G



# Description

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

# Features

- Blocking Voltage to 800 V
- On-State Current Rating of 8 A RMS at 80°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dV/ dt – 2000 V/s minimum at 125°C
- Minimizes Snubber Networks for Protection

#### **Functional Diagram**



• Industry Standard TO-220AB Package • High Commutating dl/

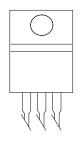
dt – 1.5 A/ms minimum at 125°C

Po

- Internally Isolated (2500) V<sub>BMS</sub>)
- These Devices are Pb-Free and are RoHS Compliant

#### **Pin Out**





# **Additional Information**







Resources

Samples

#### Maximum Ratings (T = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T <sub>J</sub> = -40° to 125°C)	BTA08–600BW3G BTA08–800BW3G	V <sub>drm</sub> , V <sub>rrm</sub>	600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_c = 80^{\circ}$ C)		I <sub>T (RMS)</sub>	8.0	А
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>c</sub> = 25°C)		I <sub>tsm</sub>	90	А
Circuit Fusing Consideration (t = 8.3 ms)		l²t	36	A <sup>2</sup> sec
Non–Repetitive Surge Peak Off–State Voltage ( $T_J = 25^{\circ}$ C, t = 10ms)		$V_{\rm DSM}/V_{\rm RSM}$	V <sub>DSM</sub> /V <sub>RSM</sub> +100	V
Peak Gate Current (T <sub>J</sub> = 125°C, t = 20ms)		I <sub>gm</sub>	4.0	А
Peak Gate Power (Pulse Width $\leq$ 1.0 µs, T <sub>c</sub> = 80°C)		P <sub>G(AV)</sub>	20	W
Average Gate Power (T <sub>J</sub> = 125°C)		P <sub>G(AV)</sub>	1.0	W
Operating Junction Temperature Range		TJ	-40 to +125	°C
Storage Temperature Range		T <sub>stg</sub>	-40 to +125	°C
RMS Isolation Voltage (t = 300 ms, R.H. $\leq$ 30%, T <sub>a</sub> = 25°C)		V <sub>iso</sub>	2500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V<sub>DRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

#### **Thermal Characteristics**

		1		
	Rating	Symbol	Value	Unit
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R <sub>ejc</sub> R <sub>eja</sub>	2.5 63	°C/W
Maximum Lead Temperature for Solder 10 seconds	TL	260	°C	

#### Electrical Characteristics - OFF (T<sub>1</sub> = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current	T <sub>1</sub> = 25°C	I <sub>DRM</sub> ,	-	-	0.005	٣A
$(V_{D} = V_{DRM} = V_{RRM}; \text{ Gate Open})$	T_ = 125°C	I	-	-	2.0	mA

#### **Electrical Characteristics** - **ON** (T = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Forward On-State Voltage (Note 2) (I $_{TM} = \pm 22.5$ A Peak)	,	V <sub>TM</sub>	-	_	1.55	V
	MT2(+), G(+)		2.5	_	50	
Gate Trigger Current (Continuous dc) (V $_{\rm D}$ = 12 V, R $_{\rm L}$ = 30 $\Omega)$	MT2(+), G(-)	I <sub>GT</sub>	2.5	_	50	mA
	MT2(-), G(-)		2.5	_	50	
Holding Current ( $V_p = 12 V$ , Gate Open, Initiating Current = ±150 mA)	'	I <sub>H</sub>	_	_	60	mA
	MT2(+), G(+)	-   I <sub>L</sub>	_	_	70	mA
Latching Current ( $V_{D} = 12$ V, $I_{G} = 50$ mA)	MT2(+), G(-)		_	_	90	
	MT2(-), G(-)		_	_	70	
	MT2(+), G(+)	V <sub>GT</sub>	0.5	_	1.7	V
Gate Trigger Voltage (V $_{\rm D}$ = 12 V, R $_{\rm L}$ = 30 $\Omega)$	MT2(+), G(-)		0.5	_	1.1	
	MT2(-), G(-)		0.5	_	1.1	
	MT2(+), G(+)	t	0.2	-	-	
Gate Non–Trigger Voltage ( $T_j = 125^{\circ}C$ )	MT2(+), G(-)		0.2	-	-	V
	MT2(-), G(-)	1	0.2	_	-	1

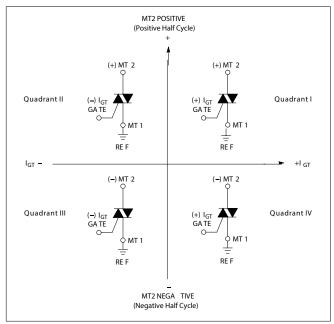
2. Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.



Dynamic Characteristics					
Characteristic	Symbol	Min	Тур	Max	Unit
Rate of Change of Commutating Current, See Figure 10. (Gate Open, $T_{\rm J}$ = 125°C, No Snubber)	(dl/dt)c	3.0	-	-	A/ms
Critical Rate of Rise of On–State Current (T <sub>J</sub> = 125°C, f = 120 Hz, I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤100 ns)	dl/dt	-	-	50	A/µs
Critical Rate of Rise of Off-State Voltage ( $V_{D} = 0.66 \times V_{DBM}$ , Exponential Waveform, Gate Open, $T_{J} = 125^{\circ}$ C)	dV/dt	1500	-	_	V/µs

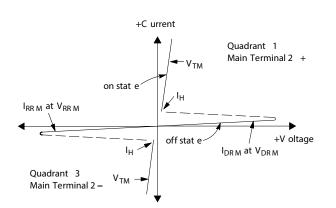
### Voltage Current Characteristic of SCR

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Forward Off State Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current

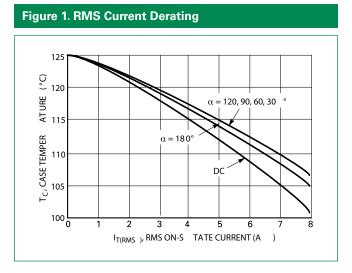


**Quadrant Definitions for a Triac** 

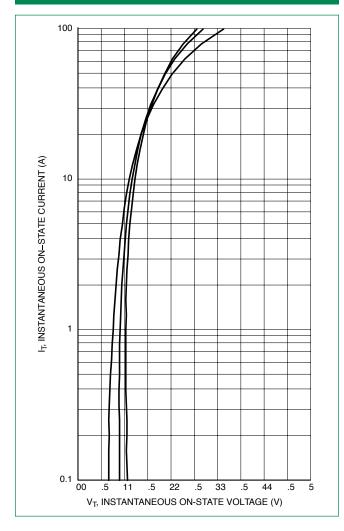
All polarities are referenced to MT1. With in–phase signals (using standard AC lines) quadrants I and III are used



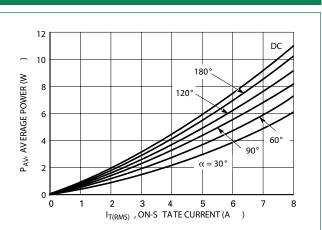




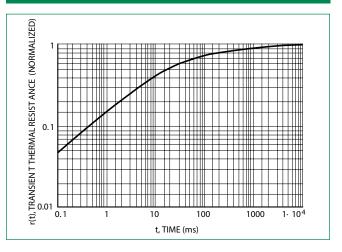
### Figure 3. On–State Characteristics



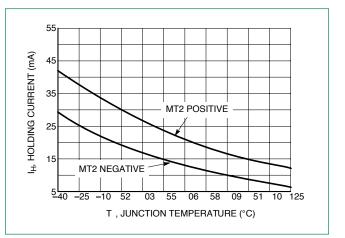
# Figure 2. On-State Power Dissipation



# Figure 4. Thermal Response

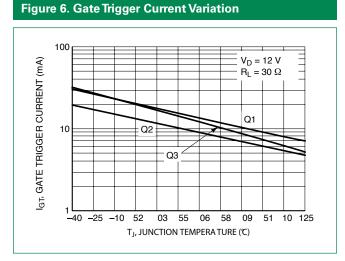


# Figure 5. Hold Current Variation

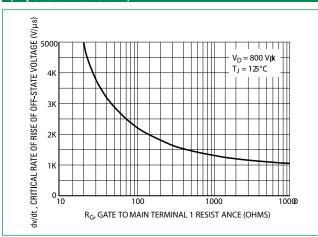




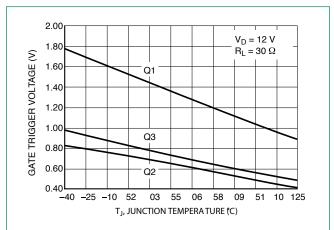
#### **Typical Characteristics**



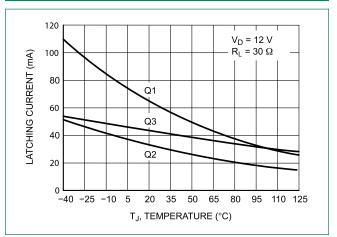
# Figure 8. Critical Rate of Rise of Off-State Voltage (Exponential Waveform)



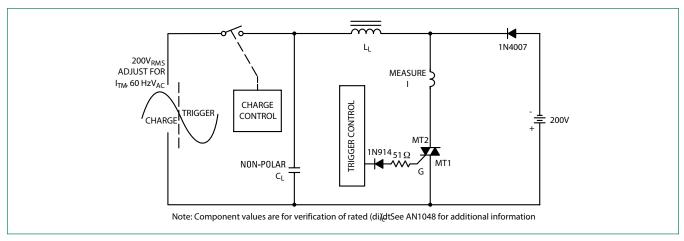
#### Figure 7. Gate Trigger Voltage Variation



### Figure 10. Latching Current Variation



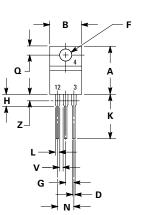
#### Figure 9. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

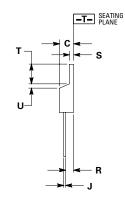


Note: Component values are for verification of rated (di/dt)c. See AN1048 for additional information

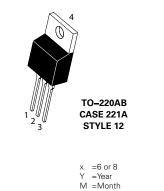


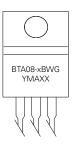
# **Dimensions**





# Part Marking System





500 Units / Retail

Inches		hes	Millimeters			
Dim	Min	Мах	Min	Мах		
Α	0.590	0.620	14.99	15.75		
В	0.380	0.420	9.65	10.67		
С	0.178	0.188	4.52	4.78		
D	0.025	0.035	0.64	0.89		
F	0.142	0.147	3.61	3.73		
G	0.095	0.105	2.41	2.67		
н	0.110	0.130	2.79	3.30		
J	0.018	0.024	0.46	0.61		
К	0.540	0.575	13.72	14.61		
L	0.060	0.075	1.52	1.91		
N	0.195	0.205	4.95	5.21		
Q	0.105	0.115	2.67	2.92		
R	0.085	0.095	2.16	2.41		
S	0.045	0.060	1.14	1.52		
т	0.235	0.255	5.97	6.47		
U	0.000	0.050	0.00	1.27		
V	0.045		1.15			
Z		0.080		2.04		

Pin Assignment			
Main Terminal 1			
Main Terminal 2			
Gate			
No Connection			

A =Assembly Site XX =Lot Serial Code G = Pb-Free Package

Ordering Information	)	
Device	Package	Shipping
BTA08-600BW3G	TO-220AB	500 Upits / Rotail

BTA08-800BW3G

(Pb-Free)

#### 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

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